Linear IC General purpose Converter cmos

D/A Converter for Digital Tuning

(8 channels. 8-bit, with OP amplifier)

MB88347

■ DESCRIPTION

The MB88347 features 8 channels of 8-bit D/A converters (with output amplifiers). The output amplifier provides high current drive capability. As data is input via a serial link, only three control lines are required, and cascaded connections can be used.

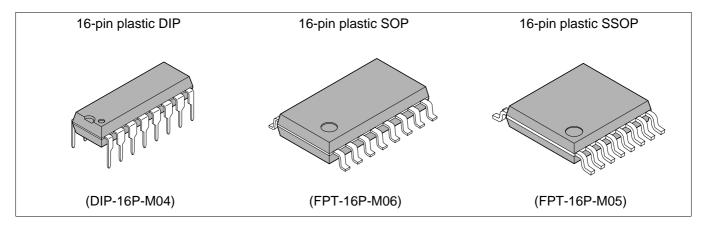
The MB88347 is suitable for electronic volumes and replacement for potentiometers for adjustment, in addition to normal D/A converter applications.

■ FEATURES

- Low power consumption (2 mW/ch)
- Small package
- Integrating 8 channels of R-2R type 8-bit D/A converter.

(Continued)

■ PACKAGES



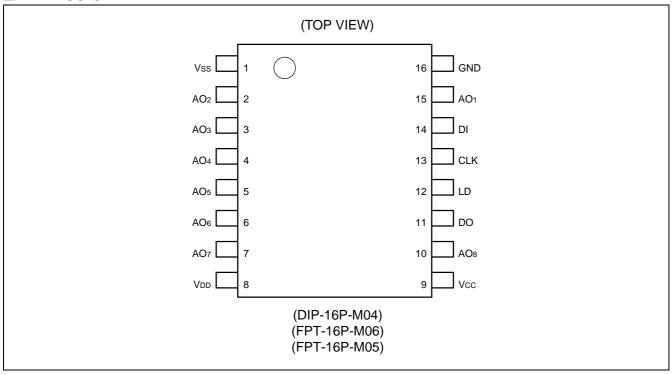


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- Built-in analog output amplifier (Max +1.0 mA sink/source current)
- Analog output range : 0 to Vcc
- The range of D/A conversion can be independently set by separated the power supply for MCU interface and OP amplifier and the power supply for D/A converter.
- Capable of being controlled directly by a 3-V MCU (input voltage : "H" = 0.5 V cc, "L" = 0.2 V cc)
- Serial data input, 2.5 MHz operation
- CMOS process
- Package lineup : DIP 16-pin, SOP 16-pin, SSOP 16-pin

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■ PIN ASSIGNMENT



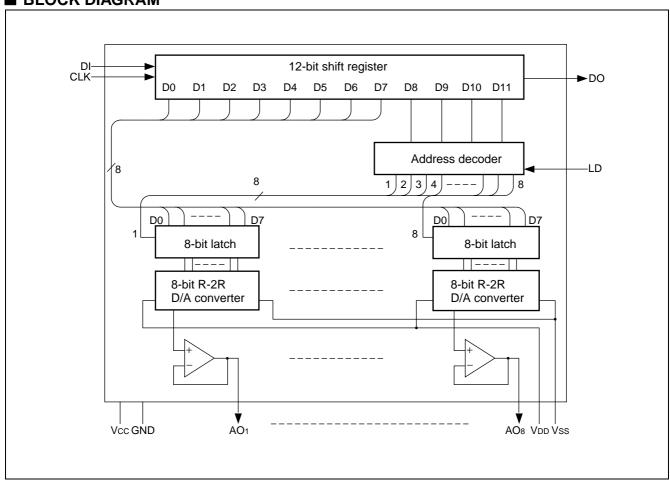
■ PIN DESCRIPTION

Pin No.	Symbol	I/O	Pin name	Function		
14	DI*	I	Data input pin	Serial data input pin. This pin inputs 12-bit length serial data.		
11	DO	0	Data output pin	This pin outputs MSB bit data of 12-bit shift register.		
13	CLK*	I	Shift clock input pin	Shift clock input pin. The input signal from the DI pin is inputted to a 12-bit shift register on the rising edge of the shift clock.		
12	LD*	I	Load signal input pin	If input "H" level to LD pin, the data of shift register is loaded to the decoder and the register for D/A output.		
15	AO ₁					
2	AO ₂					
3	АОз		<u> </u>			
4	AO ₄	0	D/A output pin	These pins are 8-bit D/A output with OP amplifier.		
5	AO ₅		D/A output pill	These pins are o-bit b/A output with Or ampliner.		
6	AO ₆					
7	AO ₇					
10	AO ₈					
9	Vcc	_	Power supply pin	Power supply pin of MCU interface and OP amplifier		
16	GND	_	Ground pin	Ground pin of MCU interface and OP amplifier		
8	V _{DD}	_	Power supply pin	Power supply pin of D/A converter		
1	Vss		Ground pin	Ground pin of D/A converter		

^{*:} DI, CLK, and LD pins are fixed to "L" level at non transfer.

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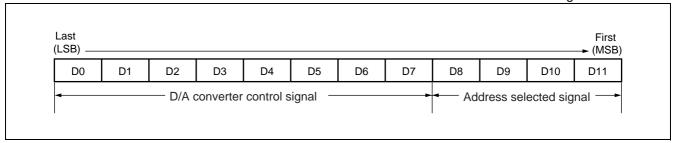
■ BLOCK DIAGRAM



■ DATA FOR CHIP CONTROL

1. Data for Shift Register

- MB88347 has 12-bit shift register for chip control.
- It is necessary to set the data as following configuration to 12-bit shift register.
- The data consists of 12 bits: a 4-bit address selection and an 8-bit D/A converter control signal.



2. D/A Converter Control Signal

			Input da	ta signal	D/A converter output voltage			
D0	D1	D2	D3	D4	D5	D6	D7	DIA converter output voltage
0	0	0	0	0	0	0	0	≑ Vss
1	0	0	0	0	0	0	0	
0	1	0	0	0	0	0	0	⇒ VLB × 2 + Vss
\$	5	5	\$	\$,	5	5	\$
0	1	1	1	1	1	1	1	
1	1	1	1	1	1	1	1	≑ V _{DD}

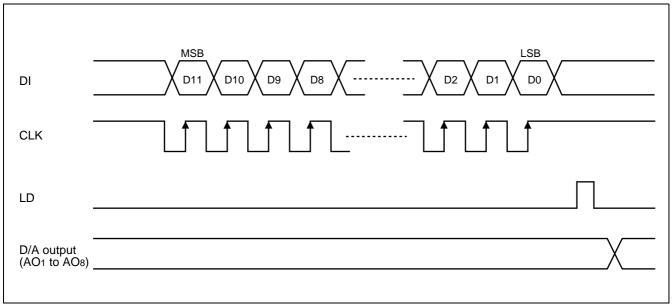
 $V_{LB} = (V_{DD} - V_{SS})/255$

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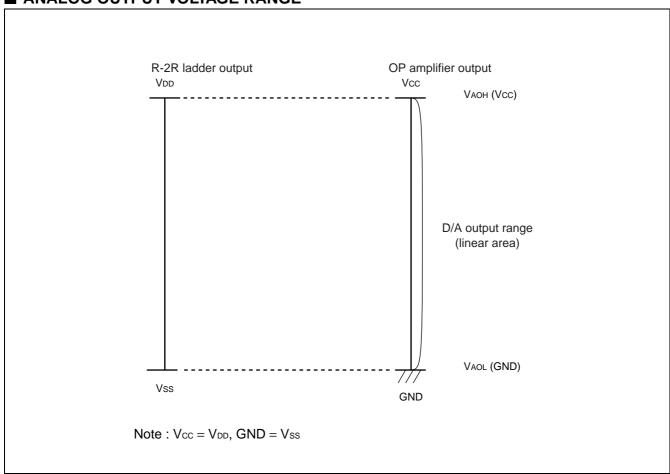
3. Address Selected Signal

	Input data signal			Address selected
D8	D9	D10	D11	Address selected
0	0	0	0	Don't Care
0	0	0	1	AO ₁ selected
0	0	1	0	AO ₂ selected
0	0	1	1	AO₃ selected
0	1	0	0	AO ₄ selected
0	1	0	1	AO₅ selected
0	1	1	0	AO ₆ selected
0	1	1	1	AO ₇ selected
1	0	0	0	AO ₈ selected
1	0	0	1	Don't Care
1	0	1	0	Don't Care
1	0	1	1	Don't Care
1	1	0	0	Don't Care
1	1	0	1	Don't Care
1	1	1	0	Don't Care
1	1	1	1	Don't Care

■ TIMING CHART AT DATA SETTING



■ ANALOG OUTPUT VOLTAGE RANGE



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Rat	Unit	
Parameter	Symbol	Condition	Min	Max	Onit
Power supply veltage	Vcc		- 0.3	+ 7.0	V
Power supply voltage	V _{DD}	The case that GND is reffered.	- 0.3*	+ 7.0*	V
Input voltage	Vin	Ta = +25 °C	- 0.3	Vcc + 0.3	V
Output voltage	Vouт		- 0.3	Vcc + 0.3	V
Power consumption	PD	_	_	250	mW
Operating temperature	Та	_	- 40	+ 85	°C
Storage temperature	Tstg	_	- 55	+ 150	°C

^{*:} $V_{CC} \ge V_{DD}$

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Condition	Va	Unit		
raiametei	Syllibol	Condition	Min	Max	J.III	
Power cumply Voltage 1	Vcc	_	4.5	5.5	V	
Power supply Voltage 1	GND	_		0	V	
Power supply Voltage 2	V _{DD}	V _{DD} – V _{SS} ≥ 2.0 V	2.0	Vcc	V	
Power supply voltage 2	Vss	VDD - VSS ≥ 2.0 V	GND	Vcc - 2.0	V	
Analog output source current	I _{AL}	_	_	1.0	mA	
Analog output sink current	Іан	_	_	1.0	mA	
Oscillation limited output capacitance	Col	_	_	1.0	μF	
Digital data setting range	_	_	#00	#FF	_	
Operating temperature	Та	_	- 40	+ 85	°C	

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

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■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics

(1) Digital block

(V_{DD}, V_{CC} = + 5 V \pm 10% (V_{CC} \geq V_{DD}) , GND, V_{SS} = 0 V, Ta = - 40 °C to + 85 °C)

Parameter	Symbol	Pin name	Pin name Conditions		Value			
Farameter	Syllibol	Fillinaine	Conditions	Min	Тур	Max	Unit	
Power supply voltage	Vcc		_	4.5	5.0	5.5	V	
Power supply current	Icc	Vcc	At CLK = 1 MHz operating (at no load) At Ta = -20 °C to $+85$ °C	_	0.8	1.8	- mA	
			At CLK = 1 MHz operating (at no load) At Ta = -40 °C to $+85$ °C		0.8	2.1		
Input leakage current	lilk	CLK	Vin = 0 to Vcc	-10	_	10	μΑ	
"L" level input voltage	VIL	DI	_	_	_	0.2 Vcc	V	
"H" level input voltage	ViH	LD	_	0.5 Vcc	_	_	V	
"L" level output voltage	Vol	DO	loL = 2.5 mA	_	_	0.4	V	
"H" level output voltage	Vон	ЪО	Іон = - 400 μА	Vcc - 0.4		—	V	

Note : IoL and IoH are output load current.

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(2) Analog block

(V_{DD}, V_{CC} = + 5 V \pm 10% (V_{CC} \geq V_{DD}) , GND, V_{SS} = 0 V, Ta = - 40 °C to + 85 °C)

Doromotor	Cymbal	Din name	n name Conditions		Value			
Parameter	Symbol	Pin name	Conditions	Min	Тур	Max	Unit	
Consumption current	IDD	V _{DD}	No load	_	1.0	1.5	mA	
Analog power	V _{DD}	V _{DD}	V _{DD} – V _{SS} ≥ 2.0 V	2.0	_	Vcc	V	
supply voltage	Vss	Vss	VDD - VSS ≥ 2.0 V	GND	_	Vcc - 2.0	V	
Resolution	Res		_	_	8	_	bit	
Monotonic increase	Rem	AO ₁ to		_	8	_	bit	
Non linearity error*1	LE	AO1 10 AO8	No load V _{DD} ≤ V _{CC} – 0.1 V	-1.5	_	1.5	LSB	
Differential linearity error*2	DLE		V _{DD} ≤ V _{CC} - 0.1 V V _{SS} ≥ 0.1 V	-1.0	_	1.0	LSB	
Output minimum voltage 1	V _A OL1		$\begin{aligned} V_{DD} &= V_{CC} \\ V_{SS} &= GND = 0.0 \ V \\ I_{AL} &= 0 \ \mu A \\ Digital \ data = \#00 \end{aligned}$	Vss	_	Vss + 0.1	V	
Output minimum voltage 2	V _A OL2		$\begin{aligned} V_{DD} &= V_{CC} = 5.0 \text{ V} \\ V_{SS} &= GND = 0.0 \text{ V} \\ I_{AL} &= 500 \mu\text{A} \\ \text{Digital data} &= \#00 \end{aligned}$	Vss - 0.2	Vss	Vss + 0.2	V	
Output minimum voltage 3	V _A OL3	AO ₁ to AO ₈	V _{DD} = V _{CC} = 5.0 V V _{SS} = GND = 0.0 V I _{AH} = 500 μA Digital data = #00	Vss	_	Vss + 0.2	V	
Output minimum voltage 4	VAOL4		V _{DD} = V _{CC} = 5.0 V V _{SS} = GND = 0.0 V I _{AL} = 1.0 mA Digital data = #00	Vss - 0.3	Vss	Vss + 0.3	V	
Output minimum voltage 5	V _A OL5		V _{DD} = V _{CC} = 5.0 V V _{SS} = GND = 0.0 V I _{AH} = 1.0 mA Digital data = #00	Vss	_	Vss + 0.3	V	

(Continued)

(V_{DD}, V_{CC} = +5 V \pm 10% (V_{CC} \geq V_{DD}) , GND, V_{SS} = 0 V, Ta = -40 °C to +85 °C)

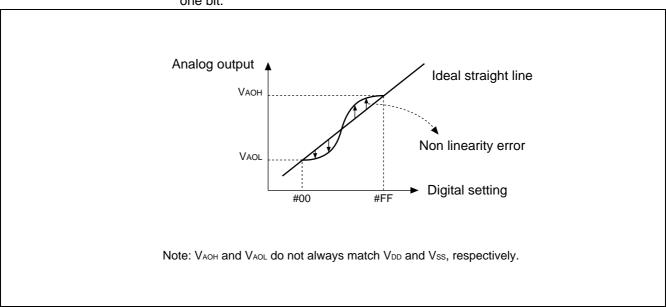
Parameter Symbo		mbol Pin name	Conditions		Unit		
Farameter	Syllibol	riii iiaiiie	Conditions	Min	Тур	Max	Ullit
Output maximum voltage 1	Vaoh1		$V_{DD} = V_{CC} \\ V_{SS} = GND = 0.0 \ V \\ I_{AL} = 0 \ \mu A \\ Digital \ data = \#FF$	V _{DD} - 0.1	_	V _{DD}	>
Output maximum voltage 2	V _A OH2		$V_{DD} = V_{CC} = 5.0 \text{ V}$ $V_{SS} = GND = 0.0 \text{ V}$ $I_{AL} = 500 \mu\text{A}$ $Digital data = \#FF$	V _{DD} - 0.2	_	V _{DD}	٧
Output maximum voltage 3	Vаонз	AO ₁ to AO ₈	$\begin{split} V_{\text{DD}} &= V_{\text{CC}} = 5.0 \text{ V} \\ V_{\text{SS}} &= \text{GND} = 0.0 \text{ V} \\ I_{\text{AH}} &= 500 \mu\text{A} \\ \text{Digital data} &= \#\text{FF} \end{split}$	V _{DD} - 0.2	V _{DD}	V _{DD} + 0.2	V
Output maximum voltage 4	Vаон4		$V_{DD} = V_{CC} = 5.0 \text{ V}$ $V_{SS} = GND = 0.0 \text{ V}$ $I_{AL} = 1.0 \text{ mA}$ Digital data = #FF	V _{DD} - 0.3	_	V _{DD}	٧
Output maximum voltage 5	Vаон5		$V_{DD} = V_{CC} = 5.0 \text{ V}$ $V_{SS} = GND = 0.0 \text{ V}$ $I_{AH} = 1.0 \text{ mA}$ Digital data = #FF	V _{DD} - 0.3	V _{DD}	V _{DD} + 0.3	V

*1 : Non linearity error :

: The error of the I/O curve from the ideal straight line between output voltages at "00"

and "FF".

*2 : Differential linearity error : The error from the ideal increment given when the digital value is incremented by one bit.



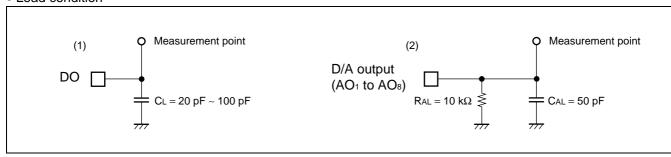
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2. AC Characteristics

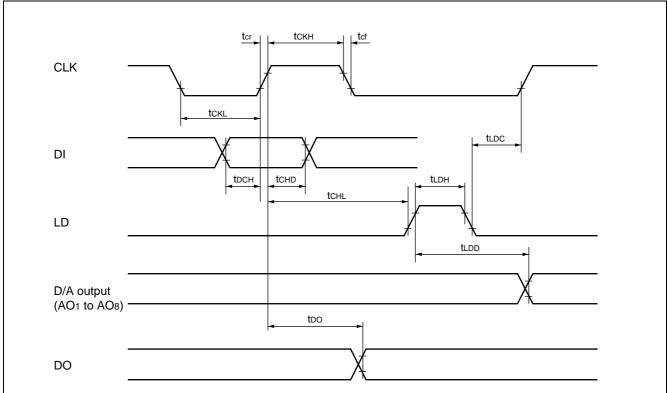
(V_{DD}, V_{CC} = + 5 V \pm 10% (V_{CC} \geq V_{DD}) , GND, V_{SS} = 0 V, Ta = - 40 °C to + 85 °C)

Parameter	Cumbal	Conditions	Va	Unit	
Parameter	Symbol	Conditions	Min	Max	Unit
"L" level clock pulse width	t ckl	_	200	_	ns
"H" level clock pulse width	t cкн	_	200	_	ns
Clock rising time Clock falling time	tcr tcf	_	_	200	ns
Data setup time	tосн	_	30	_	ns
Data hold time	t CHD	_	60	_	ns
Load setup time	t chL	_	200	_	ns
Load hold time	tldc	_	100	_	ns
"H" level load pulse width	t LDH	_	100	_	ns
Data output delay time	t DO	Refer to "Load condition (1)".	70	350	ns
D/A output settling time	t LDD	Refer to "Load condition (2)".	_	100	μs

• Load condition



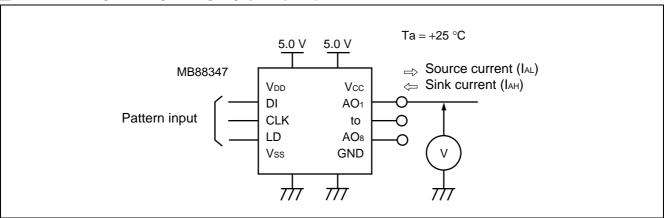


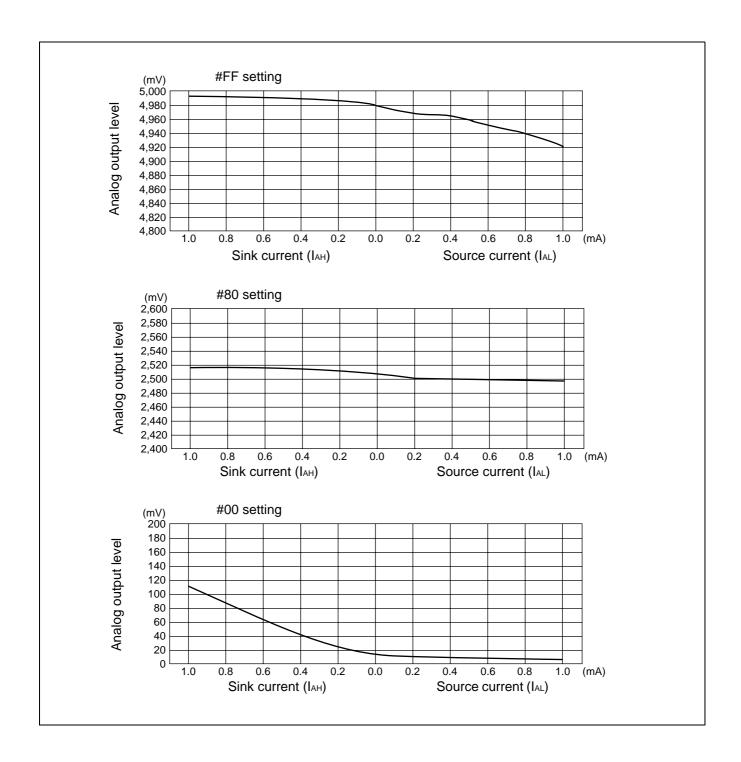


Note : The D/A output evaluation level is 90% and 10% of Vcc. The other evaluation level is 80% and 20% of Vcc.

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■ EXAMPLE CHARACTERISTIC of Vao - Iao





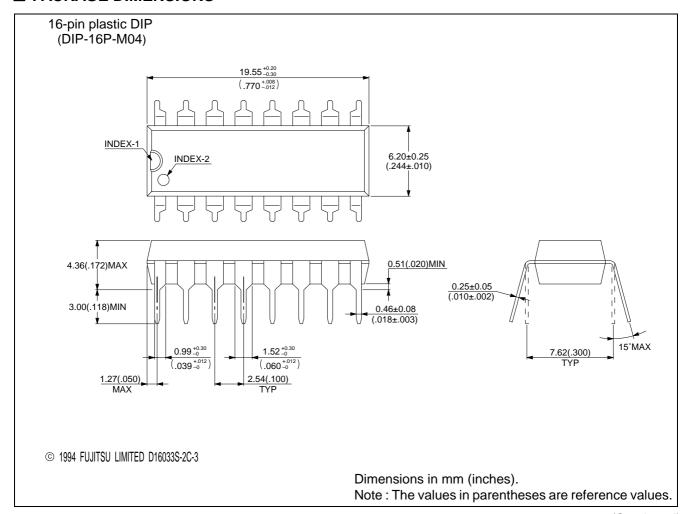
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■ ORDERING INFORMATION

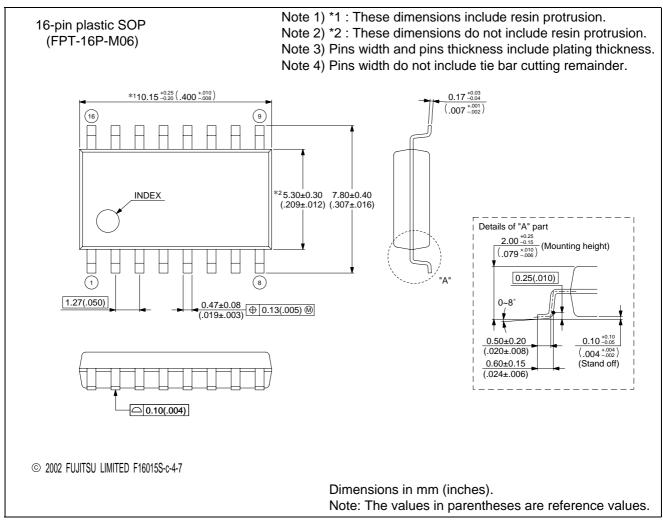
Part No.	Package	Remarks
MB88347P	16-pin plastic DIP (DIP-16P-M04)	
MB88347PF	16-pin plastic SOP (FPT-16P-M06)	
MB88347PFV	16-pin plastic SSOP (FPT-16P-M05)	

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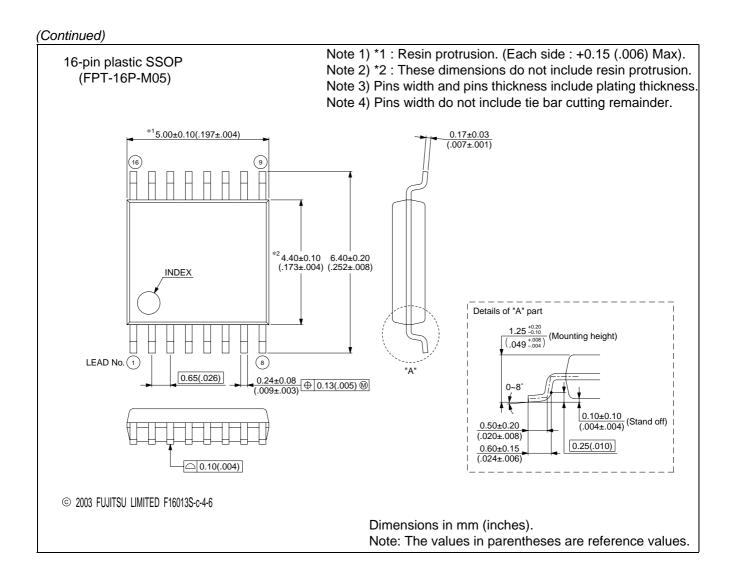
■ PACKAGE DIMENSIONS



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